
	<h2>SI7900AEDN-T1-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> SI7900AEDN-T1-E3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET 2N-CH 20V 6A 1212-8</p> <p><b>Datenblätter:</b>  <a href="#">SI7900AEDN-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 107182 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI7900AEDN-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 20V 6A 1212-8
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	107182 pcs Stock
Hersteller Standard Vorlaufzeit	33 Weeks
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) Common Drain 20V
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.5W
Verpackung / Gehäuse	PowerPAK® 1212-8 Dual
Supplier Device-Gehäuse	PowerPAK® 1212-8 Dual
Typ FET	2 N-Channel (Dual) Common Drain
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A
Rds On (Max) @ Id, Vgs	26 mOhm @ 8.5A, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)
Basisteilenummer	SI7900
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7900AEDN-T1-E3TR

SI7900AEDN-T1-E3 ist neu im Original, Suche SI7900AEDN-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7900AEDN-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7900AEDN-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI7900AEDN-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 6A PPAK 1212-8</p>	 <p><b>SI7900EDIV-T1-E3</b> VISHAY VISHAY QFN</p>	 <p><b>SI7900DN</b> VISHAY VISHAY QFN-8</p>	 <p><b>SI7900AEDN-T1-E3</b> Vishay / Siliconix MOSFET 2N-CH 20V 6A 1212-8</p>
 <p><b>SI7900AEDN-T1</b> VISHAY SI7900AEDN-T1 VISHAY</p>	 <p><b>SI7900AEDN-T1-GE3</b> Vishay / Siliconix MOSFET 2N-CH 20V 6A PPAK 1212-8</p>	 <p><b>SI7900EDM</b> VISHAY VISHAY DFN</p>	 <p><b>SI7900AEDA-T1-E3</b> VISHAY VISHAY VSSOP-8</p>

heiße Teile

Mehr

<ul style="list-style-type: none"> <li>⊕ SI7886DP-T1-E3</li> <li>⊖ SI7888DP-T1-GE3</li> <li>⊕ SI7892BDP-T1-E3</li> <li>D SI7892DP-T1-E3</li> <li>⇒ SI7898DP-T1-GE3</li> <li>↔ SI7900AEDN-T1-E3</li> <li>⊕ SI7900EDN-T1-E3</li> <li>⊖ SI7904BDN-T1-E3</li> <li>⊕ SI7904DN-T1</li> <li>↔ SI7905DN-T1-GE3</li> </ul>	<ul style="list-style-type: none"> <li>↔ SI7886DP-T1-GE3</li> <li>⊕ SI7892ADP-T1-E3</li> <li>⊖ SI7892BDP-T1-GE3</li> <li>⊕ SI7892DP-T1-GE3</li> <li>↔ SI7898DP-T1-GE3</li> <li>⇒ SI7900AEDN-T1-GE3</li> <li>D SI7900EDN-T1-GE3</li> <li>⊕ SI7904BDN-T1-E3</li> <li>⊖ SI7904DN-T1-E3</li> <li>⊕ SI7905DN-T1-GE3</li> </ul>	<ul style="list-style-type: none"> <li>⇒ SI7888DP-T1-E3</li> <li>D SI7892ADP-T1-GE3</li> <li>⊕ SI7892BDP-T1-GE3</li> <li>⊖ SI7898DP</li> <li>⊕ SI7900ADN</li> <li>D SI7900AEDN-T1-GE3</li> <li>⇒ SI7901EDN-T1</li> <li>↔ SI7904BDN-T1-GE3</li> <li>⊕ SI7904DN-T1-E3</li> <li>⊖ SI7909DN-T1-E3</li> </ul>	<ul style="list-style-type: none"> <li>D SI7888DP-T1-E3</li> <li>⇒ SI7892ADP-T1-GE3.</li> <li>↔ SI7892DP</li> <li>⊕ SI7898DP-T1-E3</li> <li>⊖ SI7900AEDN</li> <li>⊕ SI7900EDN</li> <li>↔ SI7901EDN-T1-E3</li> <li>⇒ SI7904BDN-T1-GE3</li> <li>D SI7904DN-T1-GE3</li> <li>⊕ SI7909DN-T1-E3</li> </ul>	<ul style="list-style-type: none"> <li>⇒ SI7888DP-T1-GE3</li> <li>⇒ SI7892BDP-T1-E3</li> <li>⇒ SI7892DP-T1</li> <li>⇒ SI7898DP-T1-E3</li> <li>⇒ SI7900AEDN-T1</li> <li>⊖ SI7900EDN-T1</li> <li>⇒ SI7901EDN-T1-E3</li> <li>⇒ SI7904DN</li> <li>⇒ SI7904DN-T1-GE3</li> <li>⇒ SI7909DN-T1-GE3</li> </ul>
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